

# Analog Devices Welcomes Hittite Microwave Corporation

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## GaAs MMIC ANALOG VARIABLE GAIN AMPLIFIER, 6 - 17 GHz

### Typical Applications

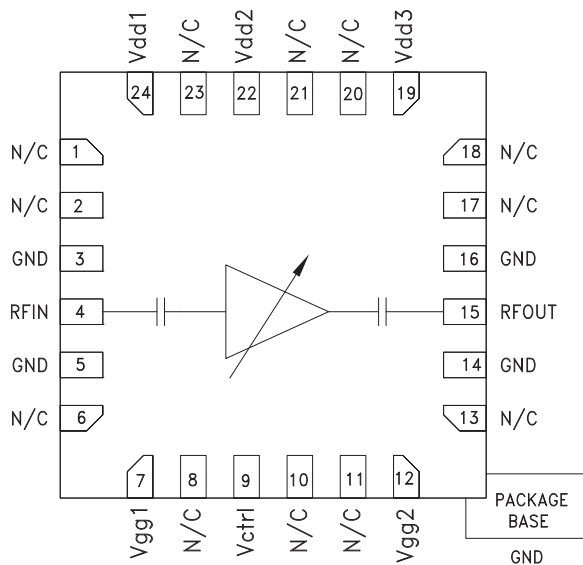
The HMC694LP4(E) is ideal for:

- Point-to-Point Radio
- Point-to-Multi-Point Radio
- EW & ECM
- X-Band Radar
- Test Equipment

### Features

- Wide Gain Control Range: 23 dB
- Single Control Voltage
- Output IP3 @ Max Gain: +30 dBm
- Output P1dB: +22 dBm
- No External Matching
- 24 Lead 4x4 mm SMT Package: 16 mm<sup>2</sup>

### Functional Diagram



### General Description

The HMC694LP4(E) is a GaAs MMIC PHEMT analog variable gain amplifier which operates between 6 and 17 GHz. Ideal for microwave radio applications, the amplifier provides up to 22 dB of gain, output P1 dB of up to +22 dBm, and up to +30 dBm of output IP3 at maximum gain, while requiring only 175 mA from a +5V supply. A gate bias pin (Vctrl) is provided to allow variable gain control up to 23 dB. Gain flatness is excellent making the HMC694LP4E ideal for EW, ECM and radar applications. The HMC694LP4E is housed in a RoHS compliant 4x4 mm QFN leadless package and is compatible with high volume surface mount manufacturing.

### Electrical Specifications, $T_A = +25^\circ\text{C}$ , $V_{dd1, 2, 3} = 5\text{V}$ , $V_{ctrl} = -2\text{V}$ , $I_{dd} = 170\text{mA}^*$

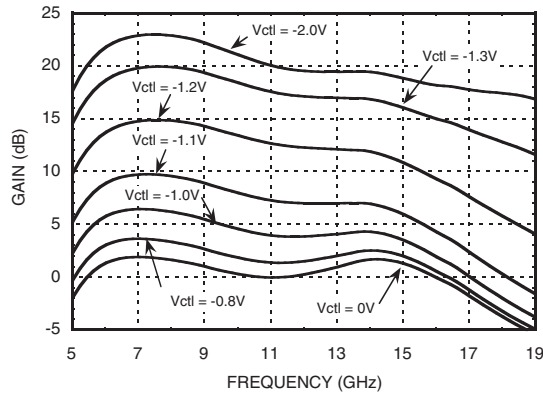
Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range		6 - 10		10 - 17			GHz
Gain	19	22		14	18		dB
Gain Flatness		$\pm 1$			$\pm 1.5$		dB
Gain Variation Over Temperature		0.015			0.015		dB/ °C
Gain Control Range		23			20		dB
Noise Figure		6	7.5		6	6.5	dB
Input Return Loss		15			8		dB
Output Return Loss		10			8		dB
Output Power for 1 dB Compression (P1dB)	19	21		21	22		dBm
Saturated Output Power (Psat)		22			23		dBm
Output Third Order Intercept (IP3)		30			30		dBm
Total Supply Current (Idd)		175			175		mA

\*Set Vctrl = -2V and then adjust Vgg1, 2 between -2V to 0V (typ. -0.8V) to achieve Idd = 170mA typical.

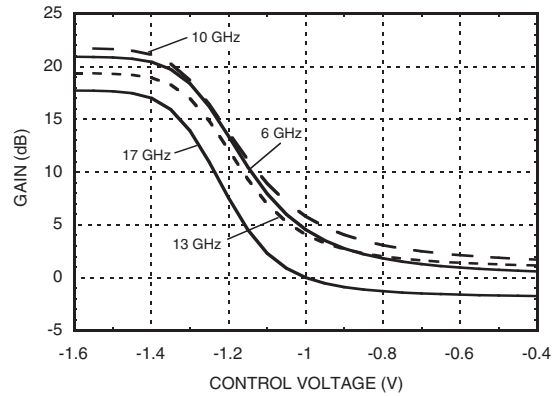


**GaAs MMIC ANALOG VARIABLE GAIN AMPLIFIER, 6 - 17 GHz**

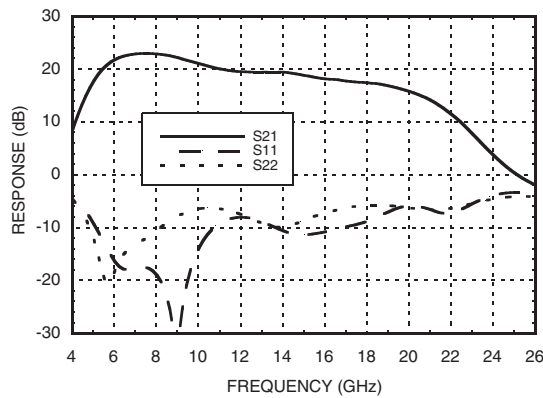
**Control Voltage Range vs. Gain**



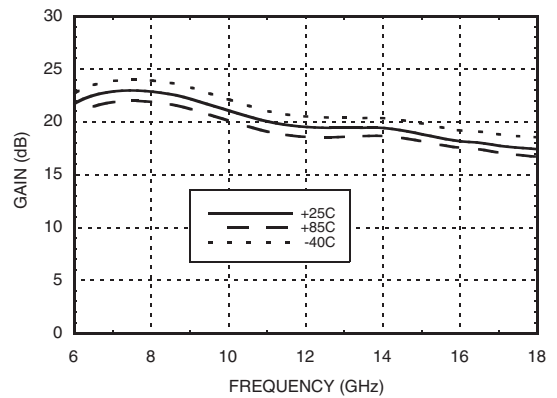
**Gain vs. Control Voltage**



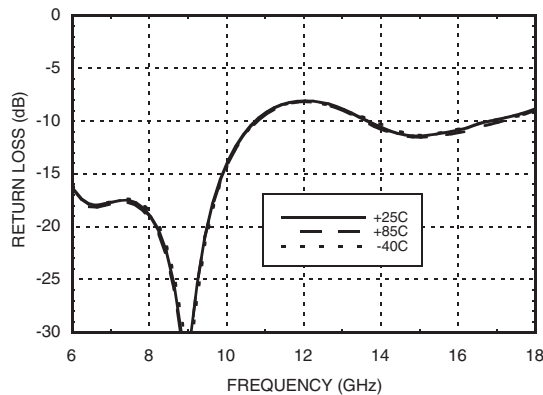
**Broadband Gain & Return Loss**



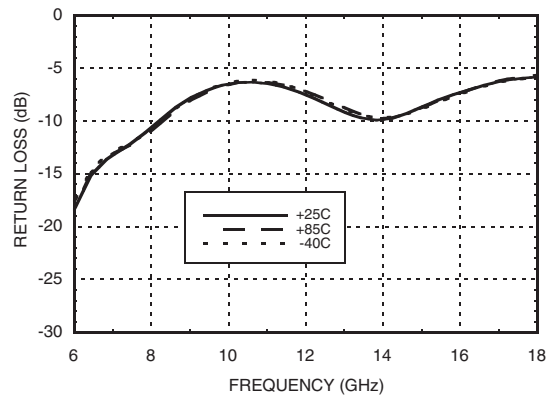
**Gain vs. Temperature**



**Input Return Loss vs. Temperature**



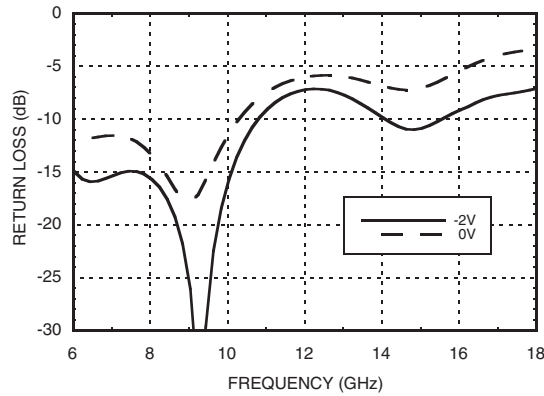
**Output Return Loss vs. Temperature**



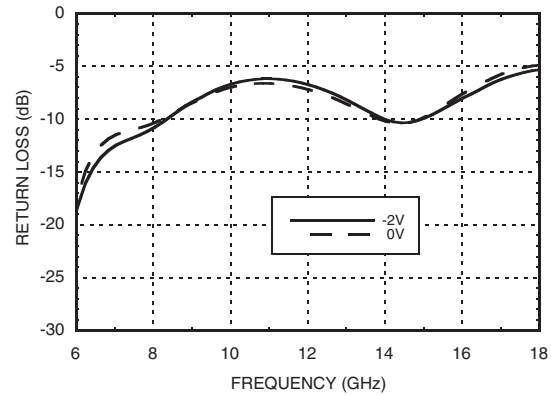


## GaAs MMIC ANALOG VARIABLE GAIN AMPLIFIER, 6 - 17 GHz

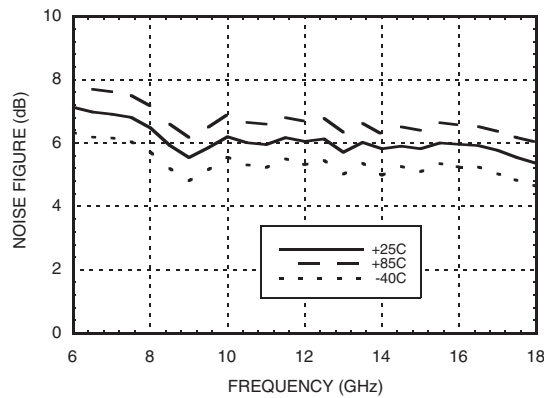
**Return Loss @ Voltage Extreme**



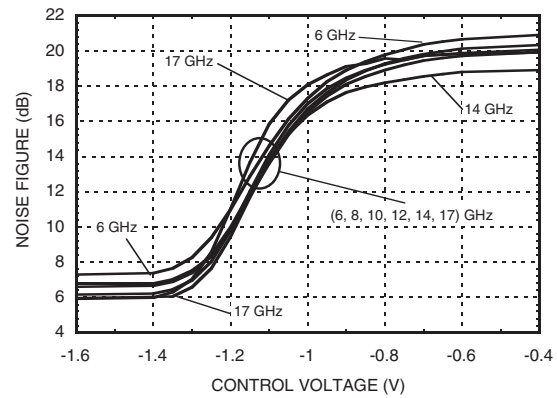
**Output Return Loss @ Voltage Extreme**



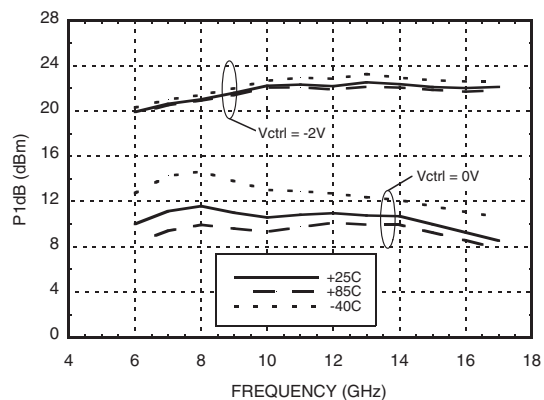
**Noise Figure vs. Temperature**



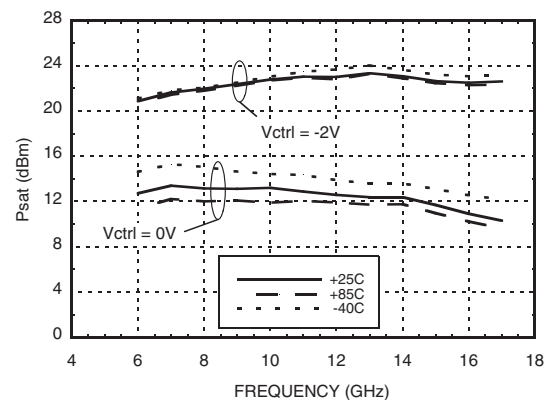
**Noise Figure vs. CTRL**



**P1dB vs. Temperature**



**Psat vs. Temperature**



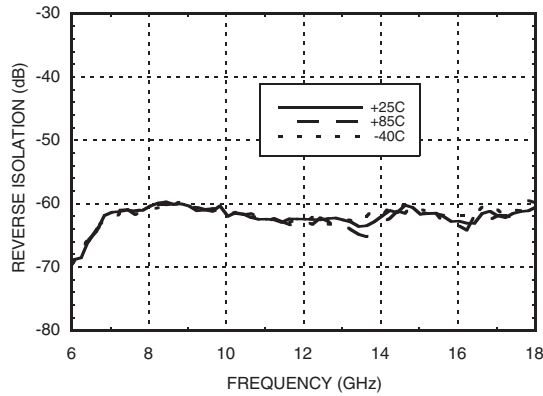
[1] Tested with broadband bias tee on RF ports and C1 = 10,000pF

[2] C1, C6 and C8 = 100pF, L1 = 24nF

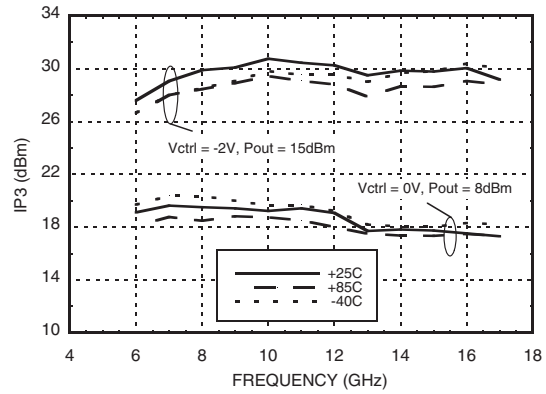


**GaAs MMIC ANALOG VARIABLE GAIN AMPLIFIER, 6 - 17 GHz**

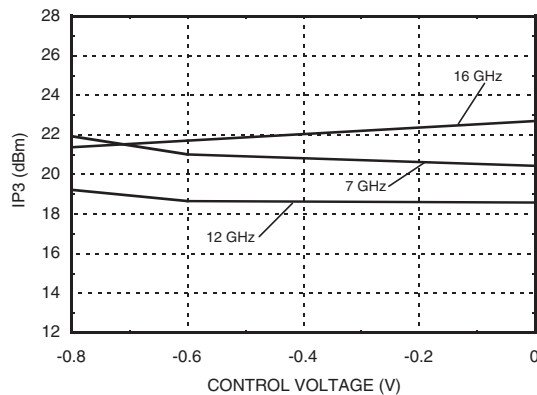
**Reverse Isolation vs. Temperature**



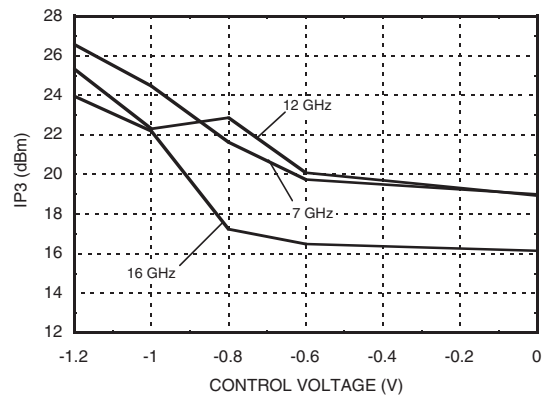
**Output IP3 vs. Temperature**



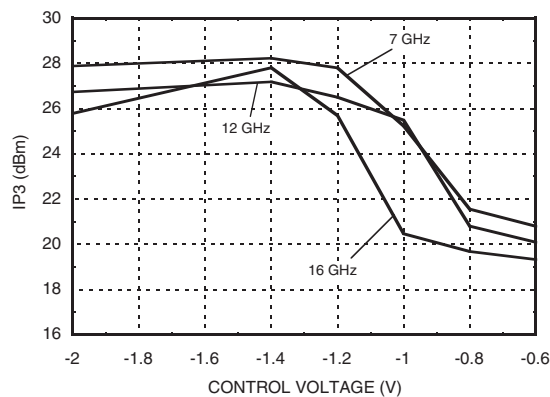
**Output IP3 @ 0 dBm**



**Output IP3 @ 5 dBm**



**Output IP3 @ 10 dBm**



### Absolute Maximum Ratings

Drain Bias Voltage (Vdd1, 2, 3)	+5.5V
Gate Bias Voltage (Vgg1, 2)	-3 to 0V
Gain Control Voltage (Vctrl)	-3 to 0V
RF Power Input	+5 dBm
Channel Temperature	175 °C
Continuous P <sub>diss</sub> (T = 85 °C) (derate 10.2 mW/°C above 85 °C) [1]	0.92 W
Thermal Resistance (Channel to ground paddle)	97.6 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

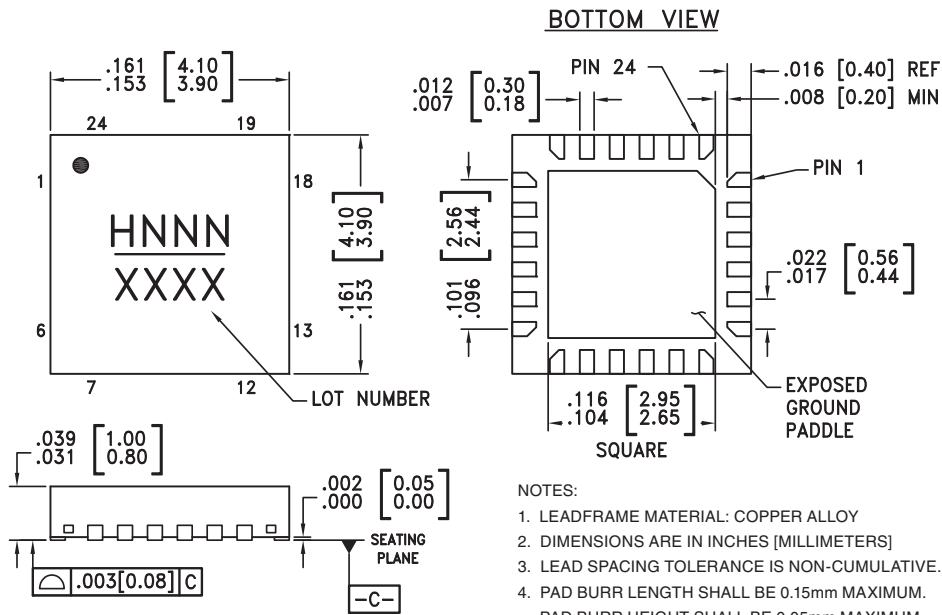
### Bias Voltage

Vdd1,2,3 (V)	I <sub>dd</sub> Total (mA)
+5.0	170
Vgg1,2 (V)	I <sub>gg</sub> Total (mA)
0V to -2V	<3 μA



ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS

### Outline Drawing



#### NOTES:

- LEADFRAME MATERIAL: COPPER ALLOY
- DIMENSIONS ARE IN INCHES [MILLIMETERS]
- LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.  
PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

### Package Information


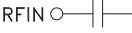
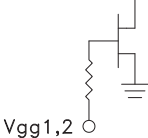
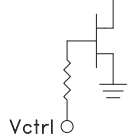
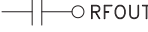
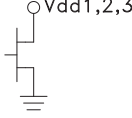
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC694LP4	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H694 XXXX
HMC694LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	H694 XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

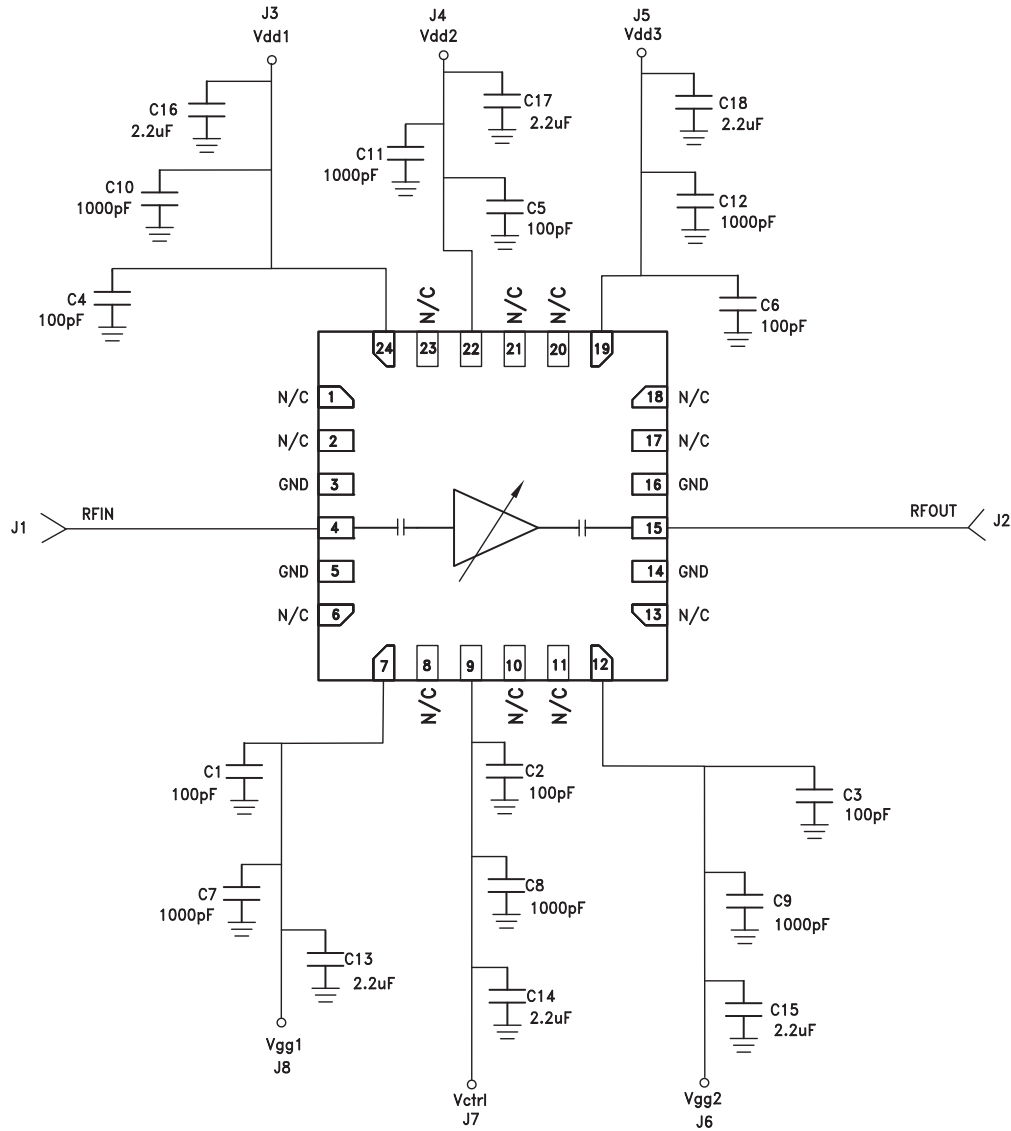

**Pin Descriptions**

Pad Number	Function	Description	Interface Schematic
1, 2, 6, 8, 10, 11, 13, 17, 18, 20, 21, 23	N/C	No Connection	
3, 5, 14, 16	GND	Die bottom must be connected to RF/DC ground.	
4	RFIN	This pad is AC coupled and matched to 50 Ohm.	
7, 12	Vgg1, 2	Gate control for amplifier. Adjust voltage to achieve typical I <sub>dd</sub> . Please follow "MMIC Amplifier Biasing Procedure" application note.	
9	Vctrl	Gain control Voltage for the amplifier. See assembly diagram for required external components.	
15	RFOUT	This pad is AC coupled and matched to 50 Ohm.	
19, 22, 24	Vdd1, 2, 3	Drain Bias Voltage for the amplifier. See assembly diagram for required external components	

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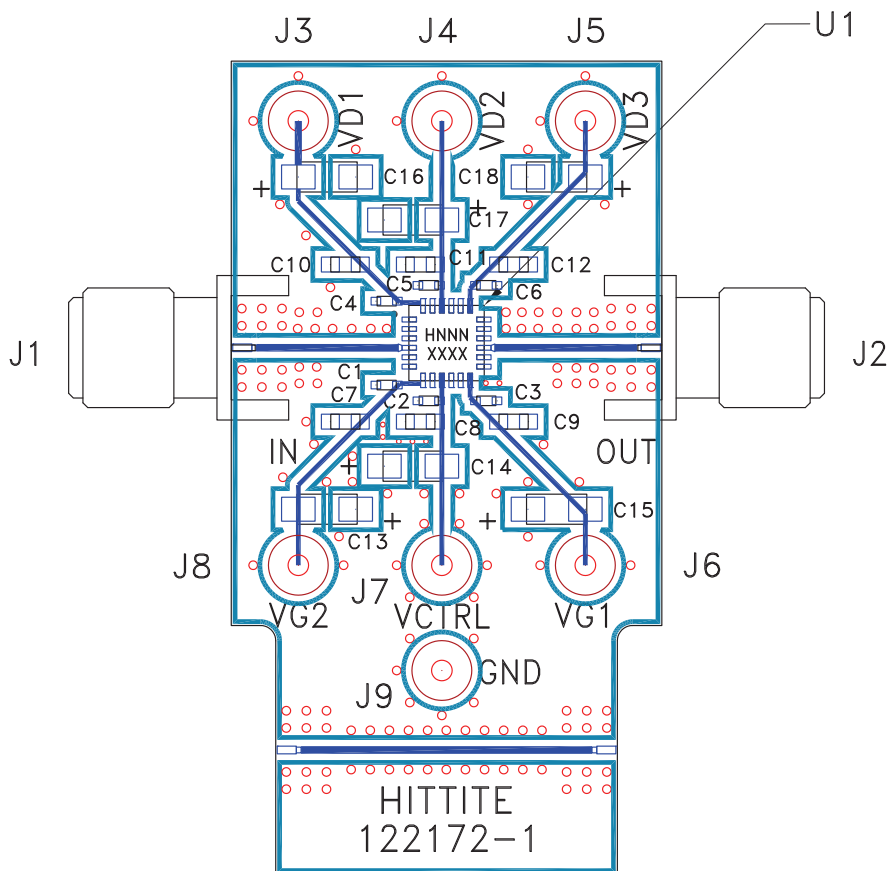
### Application Circuit



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VARIABLE GAIN AMPLIFIERS - ANALOG - SMT

### Evaluation PCB



### List of Materials for Evaluation PCB 122174 [1]

Item	Description
J1, J2	PCB Mount SMA RF Connectors
J3 - J9	DC Pin
C1 - C6	100 pF Capacitor, 0402 Pkg.
C7 - C12	1000 pF Capacitor, 0603 Pkg.
C13 - C18	2.2 μF Capacitor, CASE A
U1	HMC694LP4(E) Variable Gain Amplifier
PCB [2]	122172 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.



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- Поставка более 17-ти миллионов наименований электронных компонентов;
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- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

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